

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE30H15WK uses advanced trench technology and design to provide excellent $R_{DS(on)}$ with low gate charge. It can be used in a wide variety of applications.

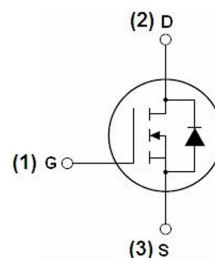
General Features

- $V_{DS} = 30V, I_D = 150A$
 $R_{DS(on)} < 2.4m\Omega @ V_{GS}=10V$
 $R_{DS(on)} < 3.5m\Omega @ V_{GS}=4.5V$
- High density cell design for ultra low $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching applications
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!
100% ΔV_{ds} TESTED!



Schematic diagram



Marking and pin assignment



Top View

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE30H15WK	NCE30H15WK	TO-252	-	-	-

Absolute Maximum Ratings ($T_C=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	150	A
Drain Current-Continuous($100^\circ C$)	$I_D(100^\circ C)$	107	A
Pulsed Drain Current ($T_C=25^\circ C$)	I_{DM}	600	A
Maximum Power Dissipation	P_D	107	W
Derating factor		0.714	W/ $^\circ C$
Single pulse avalanche energy ^(Note 1)	E_{AS}	973	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.4	$^{\circ}\text{C/W}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	50	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_c=25^{\circ}\text{C}$ unless otherwise noted)

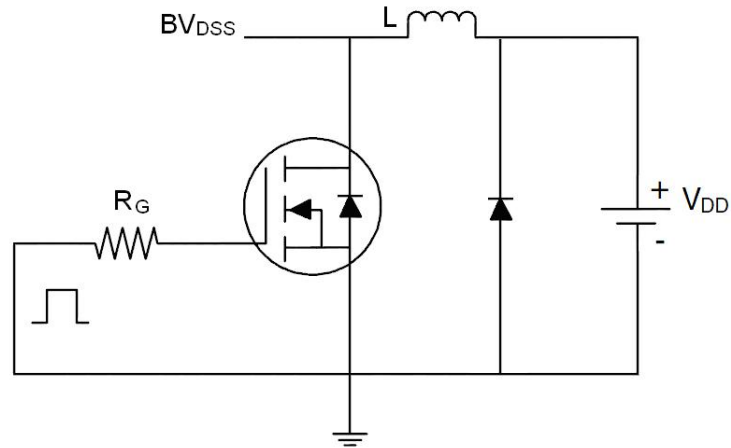
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	-	-	1	uA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.0	1.7	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A	-	2	2.4	mΩ
		V _{GS} =4.5V, I _D =20A	-	2.5	3.5	
Forward Transconductance	g _{FS}	V _{DS} =8V, I _D =13A	-	64	-	S
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =15V, V _{GS} =0V, F=1.0MHz	-	7502.7	-	PF
Output Capacitance	C _{oss}		-	808.5	-	PF
Reverse Transfer Capacitance	C _{rss}		-	671.6	-	PF
Switching Characteristics ^(Note 3)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =15V, R _L =0.5Ω, V _{GS} =10V, R _{GEN} =3Ω	-	18	-	nS
Turn-on Rise Time	t _r		-	150	-	nS
Turn-off Delay Time	t _{d(off)}		-	64	-	nS
Turn-off Fall Time	t _f		-	53	-	nS
Total Gate Charge	Q _g	V _{DS} =15V, I _D =20A, V _{GS} =10V	-	220	-	nC
Gate-Source Charge	Q _{gs}		-	17.9	-	nC
Gate-Drain Charge	Q _{gd}		-	30.6	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A	-	-	1.2	V
Diode Forward Current	I _S		-	-	150	A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = 20A di/dt = 100A/μs	-	23	-	nS
Reverse Recovery Charge	Q _{rr}		-	80	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

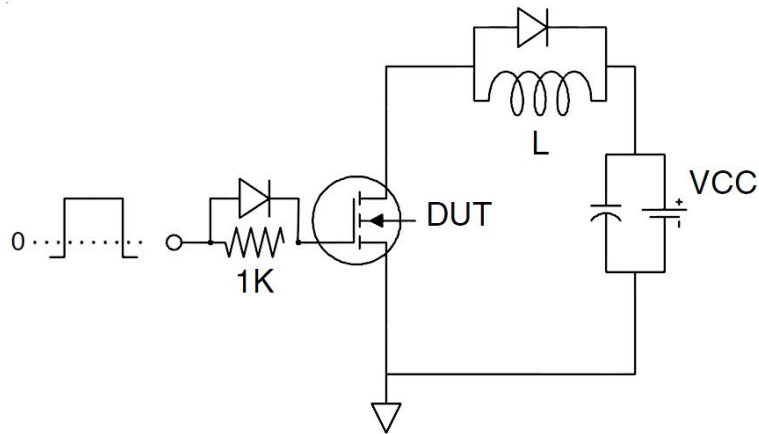
1. EAS condition : $T_J=25^{\circ}\text{C}, V_{DD}=30V, V_G=15V, L=0.5\text{mH}, R_g=25\Omega$.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}\text{C}$. The maximum allowed junction temperature of 175°C . The value in any given application depends on the user's specific board design, and the maximum temperature of 175°C may be used if the PCB allows it.
3. Guaranteed by design, not subject to production.
4. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of $T_{J(MAX)}=175^{\circ}\text{C}$. The SOA curve provides a single pulse rating.

Test Circuit

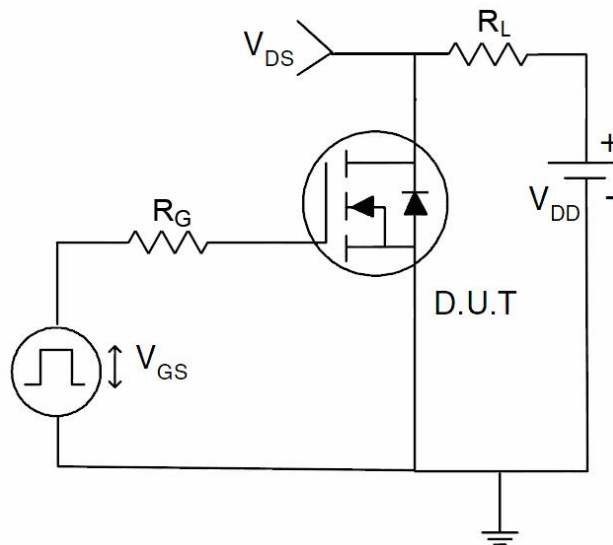
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

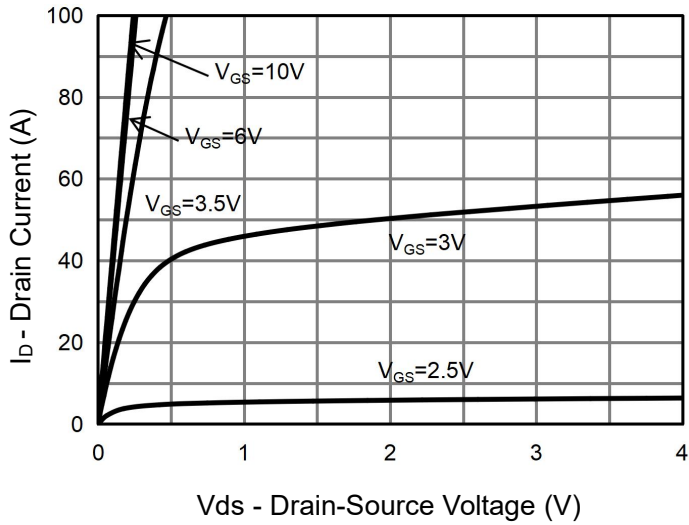


Figure 1 Output Characteristics

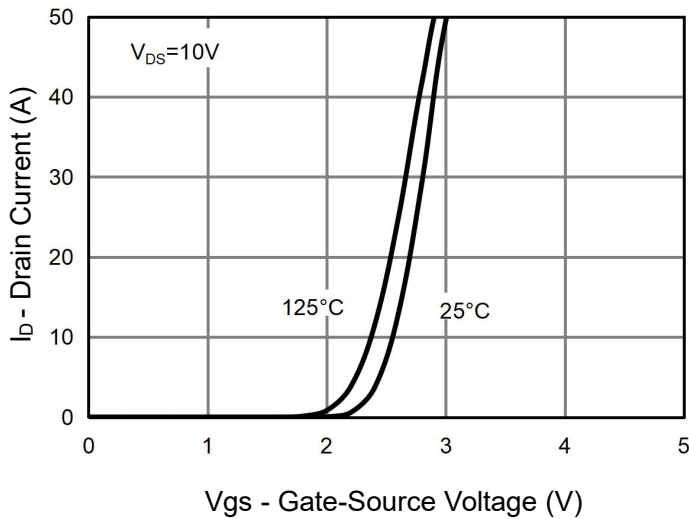


Figure 2 Transfer Characteristics

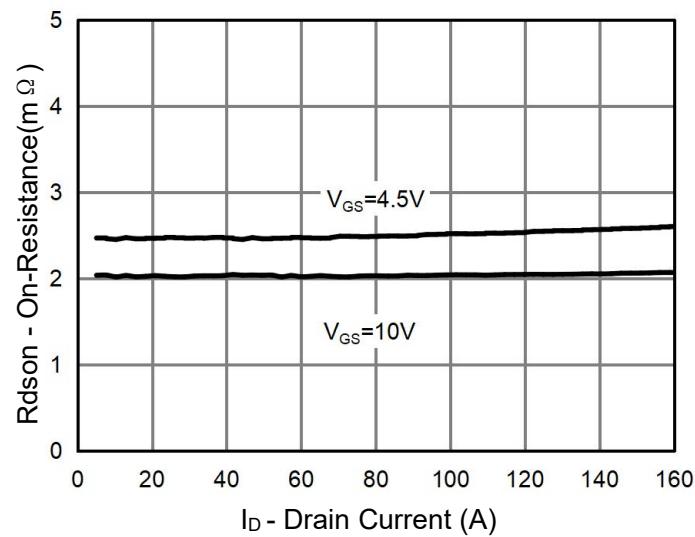


Figure 3 $R_{DS(on)}$ vs Drain Current

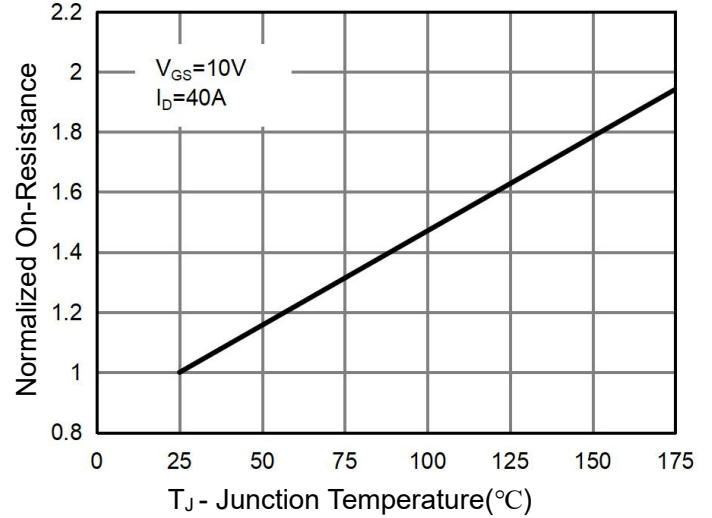


Figure 4 $R_{DS(on)}$ vs Junction Temperature

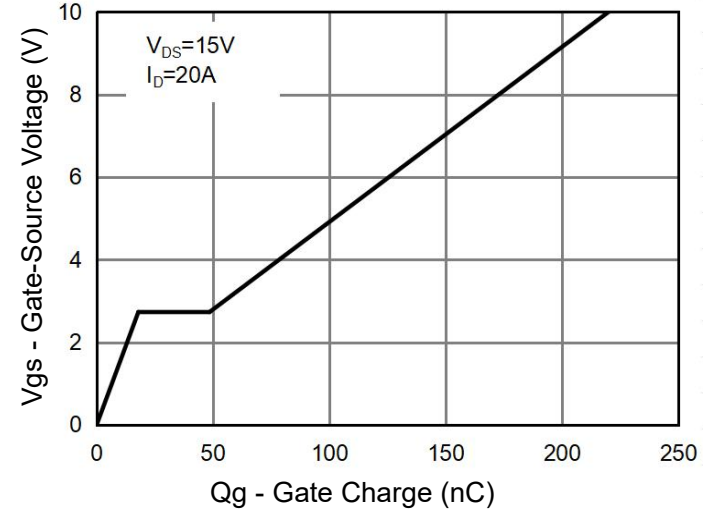


Figure 5 Gate Charge

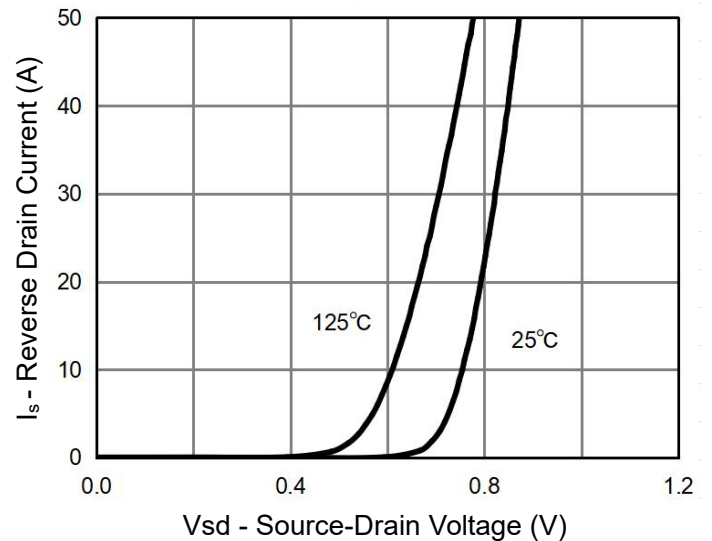
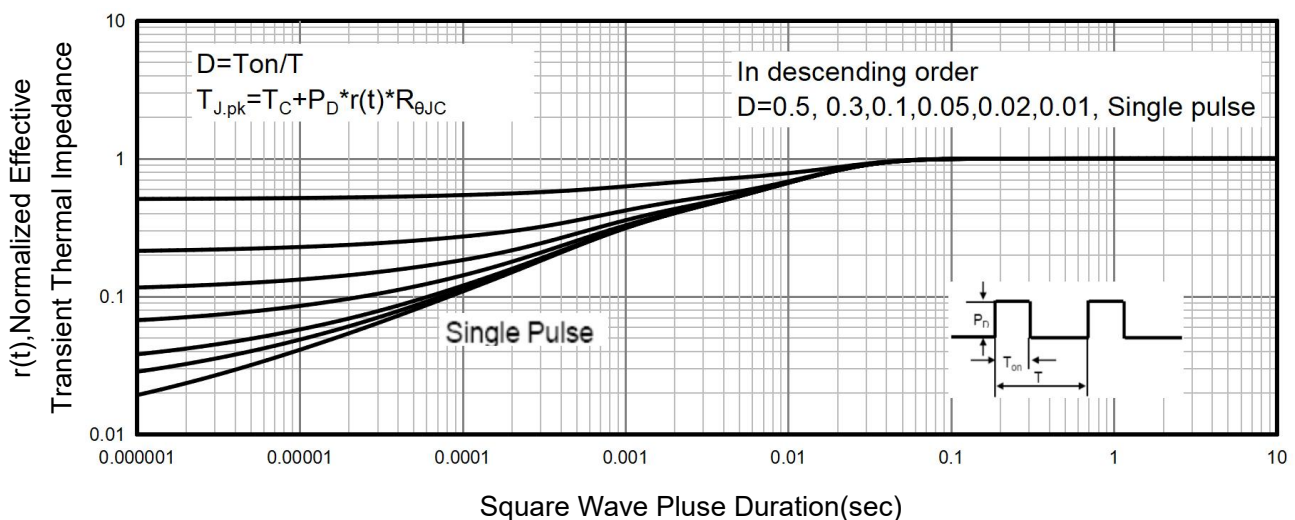
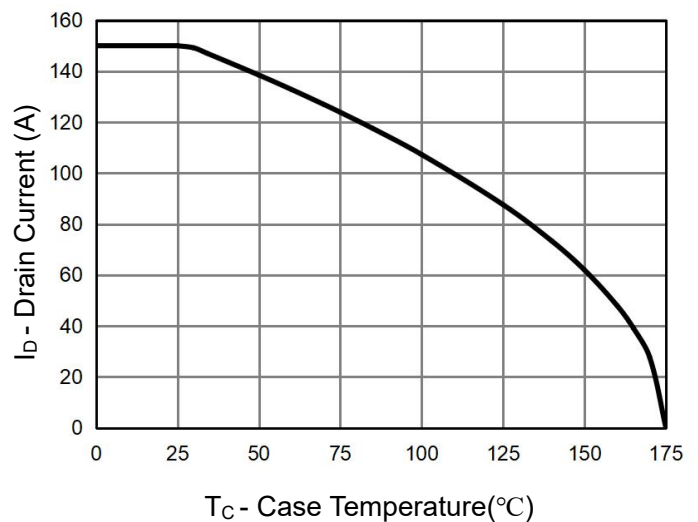
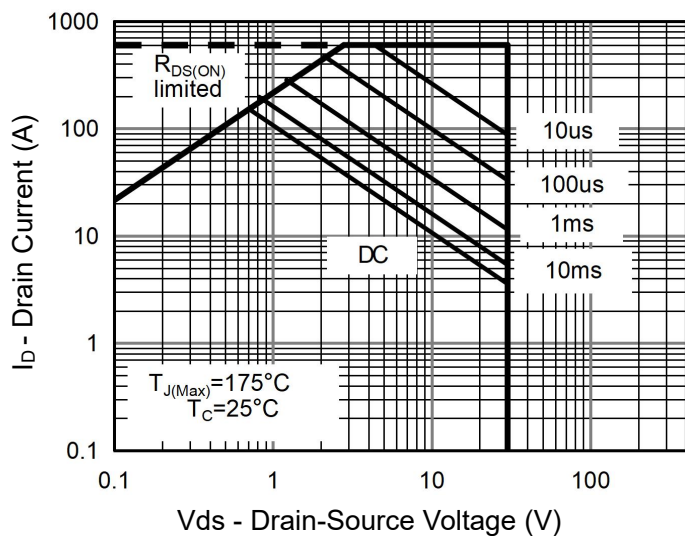
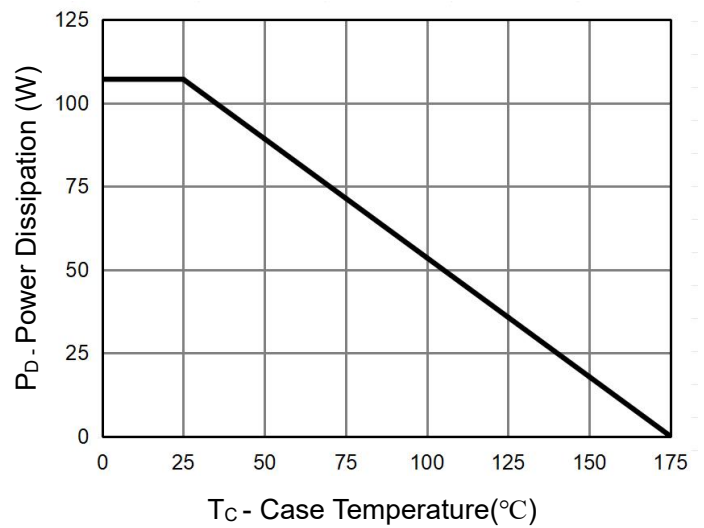
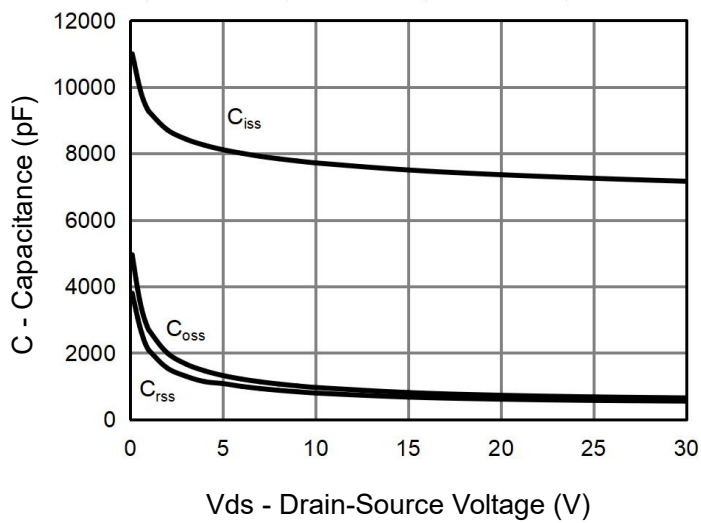
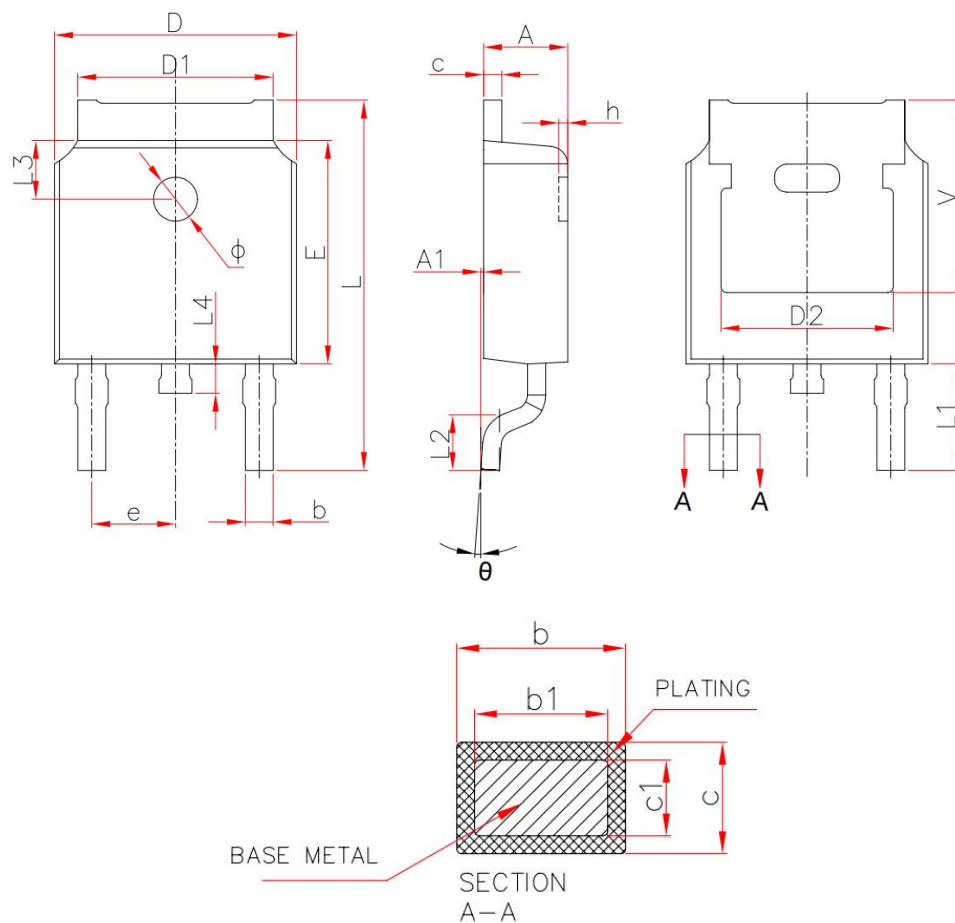


Figure 6 Source-Drain Diode Forward



TO-252 Package Information



Symbol	Millimeters	
	Min.	Max.
A	2.20	2.40
A1	0.00	0.13
b	0.66	0.86
b1	0.73	0.79
c	0.46	0.58
c1	0.50	0.52
D	6.50	6.70
D1	5.10	5.46
D2	4.83 REF.	
E	6.00	6.20
e	2.19	2.39
L	9.80	10.40
L1	2.90 REF.	
L2	1.40	1.70
L3	1.60 REF.	
L4	0.60	1.00
Φ	1.10	1.30
θ	0°	8°
h	0.00	0.30
V	5.35 REF.	

Revision History

Revision	Date	Subjects
V1.0	2025.8.15	Initial test completed

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